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Rushton, M.J.D. and Chroneos, A.

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Correspondence and requests for materials should be addressed to M.J.D.R. (m.rushton@imperial.ac.uk) or A.C. (alexander.chroneos@imperial.ac.uk)

M. J. D. Rushton¹ & A. Chroneos^{1,2}

¹Department of Materials, Imperial College London, London SW7 2AZ, United Kingdom, ²Faculty of Engineering and Computing, Coventry University, 3 Gulson Street, Coventry CV1 2JH, UK.

Doped ceria is an important electrolyte for solid oxide fuel cell applications. Molecular dynamics simulations have been used to investigate the impact of uniaxial strain along the $\langle 100 \rangle$ directions and rare-earth doping (Yb, Er, Ho, Dy, Gd, Sm, Nd, and La) on oxygen diffusion. We introduce a new potential model that is able to describe the thermal expansion and elastic properties of ceria to give excellent agreement with experimental data. We calculate the activation energy of oxygen migration in the temperature range 900–1900 K for both unstrained and rare-earth doped ceria systems under tensile strain. Uniaxial strain has a considerable effect in lowering the activation energies of oxygen migration. A more pronounced increase in oxygen diffusivities is predicted at the lower end of the temperature range for all the dopants considered.

The widespread commercial adoption of Solid Oxide Fuel Cells (SOFCs) requires their operation in the intermediate (500–700°C) temperature range¹. This requires ceramic electrodes and electrolytes with enhanced activity, which effectively translates to higher oxygen diffusivities². The SOFC community is investigating numerous candidate oxides for these applications for use in the next generation of intermediate temperature SOFCs (IT-SOFCs)^{3–8}.

Rare-earth doped ceria is an important electrolyte material because of its high oxygen ion diffusivity and relatively low reduction temperatures^{9–11}. In essence doping ceria with oxides such as R₂O₃ (here R = rare-earth) improves the oxygen diffusion due to the formation of oxygen vacancies, which act as vehicles for oxygen diffusion in the resultant Ce_{1-x}R_xO_{2-x/2} solid solution¹². Within the intermediate temperature range, doped ceria is advantageous in comparison to more conventional fuel cell electrolytes such as yttria stabilised zirconia as it exhibits up to 2–3 orders of magnitude higher oxygen ion conductivity^{13–16}.

Another way to increase oxygen diffusion is through strain, for example through the presence of an interface between dissimilar oxides^{17–20}. Atomic scale modelling can provide important insights on the impact of strain and doping regimes on oxygen transport in SOFC materials^{21–26}. Recent atomistic simulation studies were used to investigate the defect induced chemical expansion in ceria highlighting that it is important to properly model the elastic properties in doped ceria^{27,28}.

To accurately describe oxygen transport properties the potential model must adequately describe the thermal expansion of doped ceria with respect to the rare-earth dopant. Here we have derived a new and transferable potential model that reproduces experimentally determined thermal expansion and elastic constant values for ceria with a high degree of accuracy. This has enabled the use of molecular dynamics (MD) calculations within the present study to provide reliable predictions of how uniaxial strain affects oxygen ion diffusivity as a function of temperature and rare-earth doping (Yb, Er, Ho, Dy, Gd, Sm, Nd and La).

Results and discussion

Model validation. This work makes use of the recently developed Cooper, Rushton and Grimes potential (CRG) model, which provides an excellent description of CeO₂ and other fluorite oxides²⁹. Distinct from similar classical models^{30,31}, the CRG model includes many-body effects using a generalised form of the embedded atom method^{32–34} that allows it to successfully capture the Cauchy-violation³⁵, which is necessary for accurate reproduction of the elastic constants and consequently, the strain behaviour of fluorite oxides. In addition Cooper *et al.*²⁹ demonstrated that their model is capable of describing several thermo-mechanical properties such as specific heat and thermal expansion over a wide temperature range, making it suitable for use here. In particular, the model is able to reproduce the experimentally determined elastic constants of CeO₂ with high fidelity (see Table 4 within reference 29). For the present work, the CRG model has been extended to include

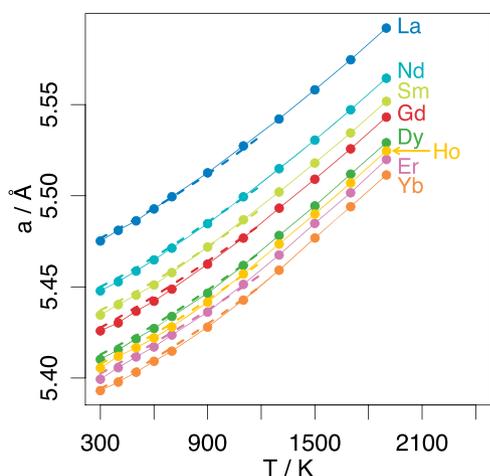


Figure 1 | Lattice parameter as a function of temperature for doped ceria ($\text{Ce}_{0.8}\text{R}_{0.2}\text{O}_{1.9}$). Solid lines show predictions made using molecular dynamics and the current potential model. The experimental data of Pikalova *et al.*³⁶ is plotted for temperatures below 1200 K as dashed lines.

interactions for a number of trivalent rare-earth species typically used as dopants within CeO_2 . The derivation of the additional interactions is described within the Methods section.

The ability of the extended CRG²⁹ model to reproduce the thermal expansion of doped ceria is illustrated in Figure 1, where lattice parameter is predicted as a function of temperature for all the dopants considered and plotted alongside Pikalova *et al.*³⁶ data. Whilst the dopant-oxygen potentials were derived at a fixed composition of $\text{Ce}_{0.8}\text{R}_{0.2}\text{O}_{1.9}$, it can be seen from Figure 2 that the model is able to predict the lattice parameter of over a wide compositional range; this figure plots lattice parameter against x for all the dopants considered at a temperature of 300 K along with experimental data^{36–40}. The predictions for the change in lattice parameter with respect to the dopant concentration obtained from the present model

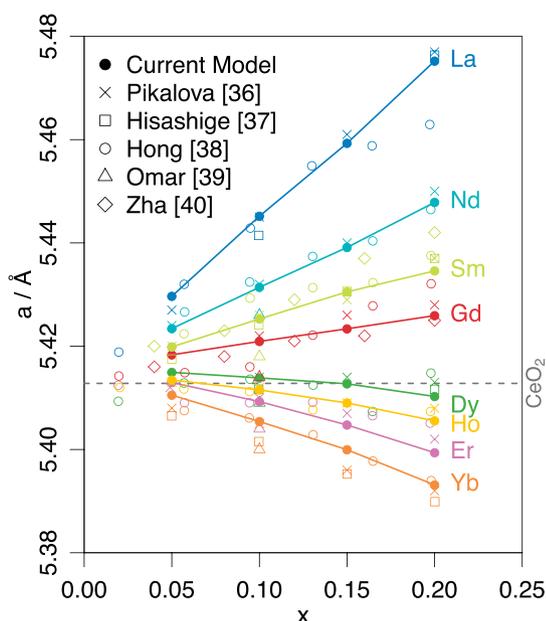
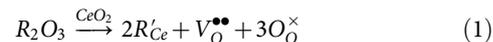


Figure 2 | Variation in lattice parameter predicted by model for $\text{Ce}_{1-x}\text{R}_x\text{O}_{2-1/2x}$ as function of dopant concentration x at $T = 300$ K. Molecular dynamics data is plotted with the experimental values^{36–40}. Dashed grey line indicates the 300 K lattice parameter predicted by the model for undoped CeO_2 .

is in very good agreement with the experimental data⁴⁰ with the predicted values falling well within the scatter of the experimental data.

Trivalent doping. The introduction of the rare-earth ions, which are trivalent, leads to the oxygen deficient $\text{Ce}_{1-x}\text{R}_x\text{O}_{2-x/2}$ solid solution. For every two rare-earth dopants introduced into the cation sublattice one oxygen vacancy is formed via the following process (given in Kröger-Vink notation⁴¹):



The formation of these oxygen vacancies is important as they are the vehicles for diffusion in the anion sublattice.

The black line in Figure 3 represents the activation energies of oxygen migration with respect to the dopant ionic radius in unstrained ceria. From the present results and the given dopant composition it is calculated that Nd-doped ceria has the lowest activation energy of oxygen migration. The low activation energy of migration for Nd-doped ceria is also reflected on the diffusivities for temperatures in the range 900–1500 K (refer to black line of Figure 4).

Impact of strain. The dependence of the activation migration energies (Figure 3) and oxygen diffusivities (Figure 4) on strain was investigated in order to show any trend relating their magnitude to dopant size and uniaxial strain. Both Figures 3 and 4 show that for all dopants, a tensile strain brings about a decrease in the activation energy of migration of between 0.052 and 0.089 eV (for 2.5% strain) to 0.096–0.182 eV (for 5% strain). Systems containing smaller dopants (such as Yb) are more sensitive to the effects of strain as compared to the larger dopants (such as La). Figure 3 reveals that at uniaxial strains up to 2.5% Nd-doped ceria has the lowest activation energy of oxygen migration (0.48 eV), whilst above 3% the minimum in the E_a vs ionic radius curve shifts towards smaller ionic radii. Most notably there is a clear minimum for Sm-doped ceria for a strain of 4%. As strain increases beyond this level, however, this minimum becomes less clearly defined as the E_a for the Gd, Sm and Nd dopants becomes increasingly similar with values of 0.421 eV, 0.417 eV and 0.423 eV respectively, at a strain of 5%.

The importance of strain on rare-earth doped ceria is even more vividly expressed by the diffusivity values shown in Figure 4. These change significantly with respect to strain, which is consistent with

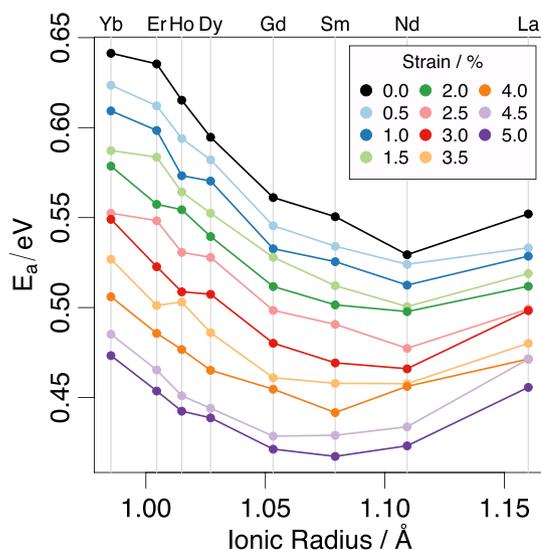


Figure 3 | The dependence of the activation energies of oxygen migration on the dopant ionic radius and strain for $\text{Ce}_{0.9}\text{R}_{0.1}\text{O}_{1.95}$.

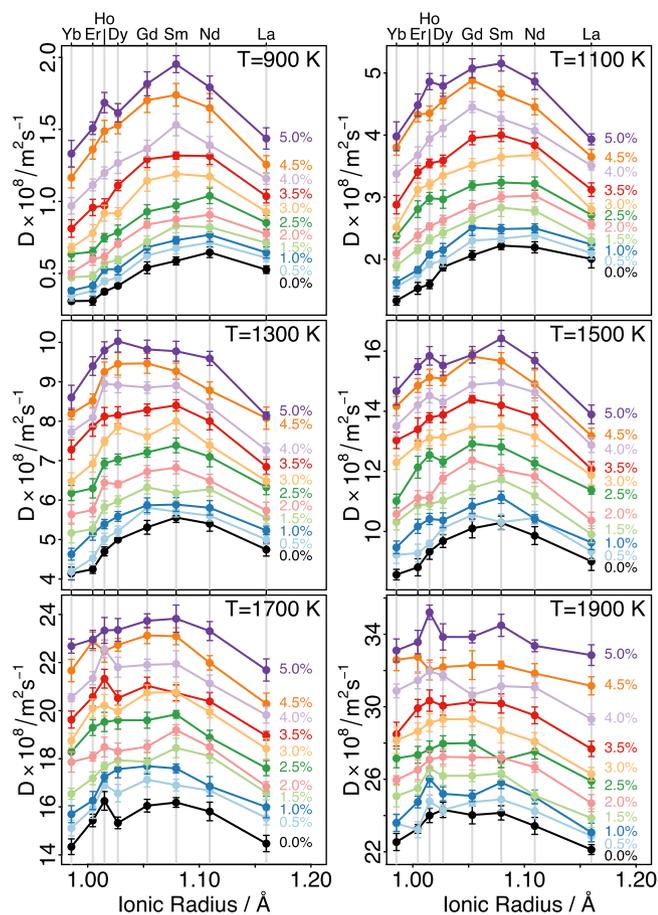


Figure 4 | The dependence of the oxygen diffusivities on the dopant ionic radius and strain.

the decrease in activation energy under tensile strain. Previous studies¹⁹ have suggested that conductivity may be increased by several orders of magnitude at strained interfaces between dissimilar oxides. Based on the results of the present study we calculate that, although considerable, the increases in oxygen diffusivity due to strain are not of the same order as these previous results may suggest (although it should be noted that biaxial conditions would be expected at such interfaces rather than the uniaxial conditions described here).

With the increase in temperature and concomitant increase in diffusivity, there is another trend that can be observed: the difference in diffusivities between dopants is decreased. This can be explained by the diminishing importance of the association between the dopants and the migrating oxygen vacancies as the T is increased. In essence, at high temperatures (above about 1000 K) the activation energy of migration of oxygen vacancies will be given by the energy barrier required for motion and will not be dependent upon the association energy of defect clusters formed between oxygen vacancies and the rare-earth dopants^{42,43}. The association energy relates to the Coulomb interactions (favouring nearest neighbour cluster configurations) and the relaxation of the ceria lattice (favouring next nearest neighbour cluster configurations)⁴⁴. Tensile strain will lead to the lowering of the association energies of clusters formed between the rare-earth dopant atoms and oxygen vacancies (whereas under compressive strain the association energies increase)²⁵. The decrease of the association energy affects smaller dopants (Yb, Er, Ho, Dy) to a larger extent than the larger dopants (Nd, La), as they are more bound under unstrained conditions⁴⁴. At increased temperatures there is a “flattening” of oxygen diffusivities in $Ce_{1-x}R_xO_{2-x/2}$ (mainly due to the reduction of the association energies of the intermediate

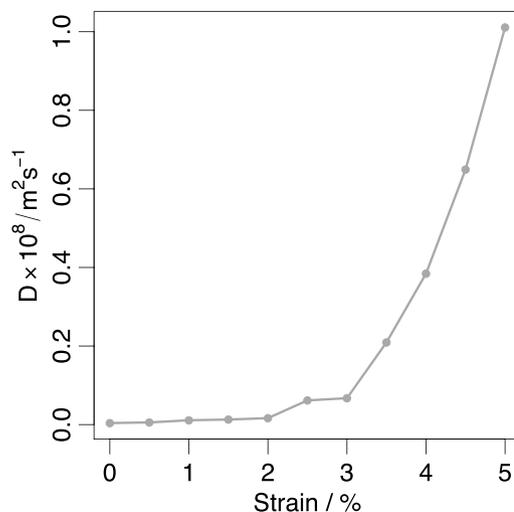


Figure 5 | Diffusion coefficient oxygen self-diffusion in undoped ceria as a function of strain at $T = 1900$ K obtained from the average of 5×5 ns duration MD simulations.

dopants: Gd, Sm) and this is nearly independent of the applied tensile strain.

Oxygen vacancy-dopant binding can only partly explain the increase in diffusivity under applied strain however, Figure 5 shows the trend in D for undoped ceria as a function of tensile strain. As for the doped cases, D values were obtained by performing a straight line fit to mean squared displacement versus time data. As the diffusion rate is much lower in the undoped case, the data in Figure 5 was collected over a longer production time of 5 ns, in order to enable statistically significant results to be obtained, even though a relatively high temperature (1900 K) was employed, furthermore the D values within Figure 5 were averaged over five such runs. For strains below 3% the D value obtained from the simulations was very small and showed no clear dependence on strain. Above this strain level, however, D increased from $6.7 \times 10^{-10} \text{ m}^2 \text{ s}^{-1}$ to a maximum of $101.1 \times 10^{-10} \text{ m}^2 \text{ s}^{-1}$ as the strain increased from 3.0% to 5.0%. This represents an increase of ~ 15 times.

As described above within doped ceria, increases in diffusivity due to strain can be attributed to a strain induced decrease in dopant-oxygen vacancy association. The results in Figure 5 are notable as they suggest that, even in the absence of such dopant-vacancy binding effects, an applied strain can lead to meaningful increases in diffusion rates. Assuming that similar mechanisms operate in both doped and undoped cases, a substantial proportion of the increase in doped ceria’s diffusivity resulting from strain may be due to effects other than dopant-vacancy binding, especially at large strains.

The uniaxial strain applied along [001] leads to anisotropic oxygen diffusion rates. Examination of the oxygen trajectories obtained during the data-collection stage of the MD simulations showed that diffusion occurred via a hopping mechanism. For both strained and unstrained cases, hops occurred between oxygen sites parallel to the [100], [010] and [001] directions. Whilst this behaviour persisted as the system was strained, the relative magnitude of the oxygen mean squared displacements along the [001] strain direction, changed in comparison to the [100] and [010] directions (which remain symmetrically equivalent even in the strained systems). This is demonstrated in Figure 6, in which the ratio of $D_{[001]}$ (the oxygen diffusion coefficient along strained direction) to the average of the diffusion coefficients perpendicular to the applied strain ($D_{[100]}$ & $D_{[010]}$) are plotted as a function of strain for three dopants. The dopants Yb, Gd and La were chosen as these span the entire range of dopant radii examined; with Yb being the smallest, La the largest and Gd having a radius intermediate between the two.

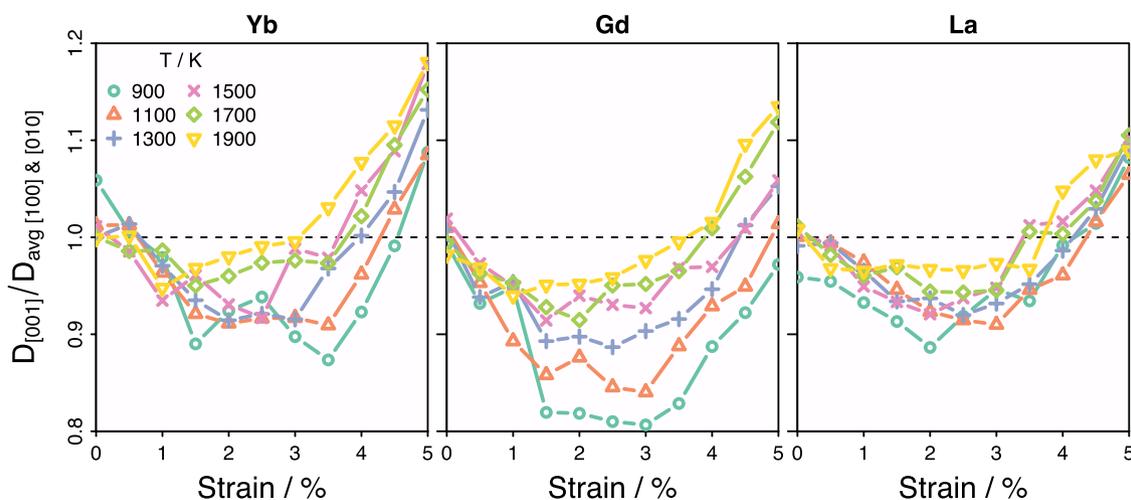


Figure 6 | Oxygen diffusion coefficient along strain direction ($D_{[001]}$) divided by that perpendicular to applied strain plotted as a function of strain. Isotropic diffusion occurs when this ratio is 1.0. When $D_{[001]}/D_{[100]\&[010]} < 1.0$ diffusion is higher in ab plane whilst values greater than unity indicate preferential diffusion along the direction of strain (c axis).

Within the uncertainty of the simulation results, Figure 6 shows that when $\varepsilon = 0$ diffusion is isotropic as $D_{[001]}/D_{\text{avg}[100] \& [010]} = 1.0$. When strain increases, however, all three dopants initially show a decrease in this ratio, which then through a minimum before increasing again. For the Yb and La systems, $D_{[001]}/D_{\text{avg}[100] \& [010]} < 1.0$ for all temperatures considered in the strain range 0–4%. When the D ratio is below unity this indicates that diffusivity was higher in the plane perpendicular to the applied strain. Within the Yb and La doped systems, when strain was above 4%, the ratio switched to become larger than 1.0 at all simulation temperatures. This suggests a change in behaviour whereby diffusivity becomes higher parallel to the strained direction (along the simulation box c axis) rather than in the ab plane as seen for low and intermediate strains.

The anisotropy of oxygen diffusion is a little different in the Gd doped system: the lower temperature curves (900 and 1100 K) do not show the distinct transition from ab plane diffusion to c axis diffusion. In particular the 900 K D ratio remains below 1.0 even at 5.0% strain, whilst the 1100 K curve is only slightly positive at 5% strain meaning the diffusion is effectively isotropic at this strain and temperature. Above 1100 K, Gd shows similar anisotropy to the Yb and La doped systems.

In summary, the present study has considered the impact of uniaxial strain and doping on oxygen diffusion in rare-earth doped CeO_2 using dynamic atomic scale computer simulation techniques. The potential model presented reproduces the thermal expansion coefficients and the variation of the lattice parameter with respect to the dopant concentration. As the temperature increases the difference in diffusivities between the rare-earth dopants is decreased and this can be traced back to the diminishing importance of the association between the dopants and the migrating oxygen vacancies. By examining undoped ceria we identify also a complementary enhancement of the diffusivity due to the impact of the imposed strain on the diffusion processes.

Methods

Model. Within this paper, the effect of uniaxial strain on doped ceria compositions was examined using MD simulations. The details of the simulation method are now given. MD allows the trajectories of an atomic configuration to be predicted with time by considering the forces between them^{45–47}. As a result the description of the interatomic forces is key to the method's success.

Whilst the CRG model includes many-bodied, electrostatic and pairwise components within its description of the O-O and Ce-O interactions, the dopant-oxygen interactions presented here, are somewhat simpler, including only long-range electrostatic and short-range pair-potential contributions. This latter short-range pair contribution (V_{short}) was described using the Born-Mayer potential form⁴⁸, such that a pair of ions, i and j , separated by a distance of r_{ij} have an energy given by:

$$V_{\text{short}}(r_{ij}) = A_{\alpha\beta} \exp\left(-\frac{r_{ij}}{\rho_{\alpha\beta}}\right) \quad (2)$$

The parameters $A_{\alpha\beta}$ and $\rho_{\alpha\beta}$ are used to tailor the short-range potential to specific pairs of interacting species α and β .

The interactions between the trivalent dopants and oxygen ions have been derived specifically for this work using an empirical fitting procedure. The $A_{\alpha\beta}$, $\rho_{\alpha\beta}$ and $C_{\alpha\beta}$ parameters for each $\text{R}^{3+}-\text{O}^{2-}$ interaction were obtained using an iterative procedure whereby the Nelder-Mead simplex minimisation algorithm⁴⁹ was used to gradually adjust potential parameters in order to improve the match between the thermal expansion data of Pikalova *et al.*³⁶ and the MD lattice parameters given by the potentials. At each iteration lattice parameters were obtained by equilibrating an $8 \times 8 \times 8 \text{ Ce}_{0.8}\text{R}_{0.2}\text{O}_{1.9}$ super-cell for 10 ps in the NPT ensemble at temperatures of 300, 600 and 1200 K. By averaging cell size over the final 2.5 ps of these runs it was possible to obtain an objective measure of how well the MD predictions matched Pikalova *et al.*³⁶ experimental data at each iteration of the simplex algorithm over the wide temperature range employed. Using this method a potential set was obtained that gives an excellent level of agreement with the experimental thermal expansion curves (a comparison between model predictions and experimental data is given in the results section), and potential parameters are given in Table 1.

Electrostatic interactions were calculated using the Particle-Particle-Particle-Mesh (PPPM) solver based on the method of Hockney and Eastwood⁵⁰ and implemented within the LAMMPS simulation code^{51,52}. In line with the partial charges employed by the CRG model²⁹, trivalent dopant ions were assigned charges of +1.6656e and Ce and O had charges of +2.2208e and $-1.1104e$ respectively. A short-range potential cut-off of 11Å was used throughout. In addition the MD calculations employed periodic boundary conditions.

All simulation boxes were based on an $8 \times 8 \times 8 \text{ CeO}_2$ super-cell. To obtain the desired dopant concentration trivalent dopant ions are substituted on to Ce sites at random with an oxygen vacancy introduced for every two dopant ions, by the random removal of an oxygen atom from the simulation cell (see equation 1). For the $x = 0.1$ cells this results in a cell containing the following atom totals: $\text{R}^{3+} \times 204$, $\text{Ce} \times 1884$ and $\text{O} \times 3994$ (i.e. $V_{\text{O}}^{\times} \times 102$).

In order to examine its on oxygen migration it was necessary to apply tensile strains of between 0–0.05 to the CeO_2 . For each combination of dopant and temperature, strained systems were generated for each 0.005 strain increment within this range.

Table 1 | Potential parameters for trivalent dopant ions

Interaction	$A_{\alpha\beta}/\text{eV}$	$\rho_{\alpha\beta}/\text{\AA}$
Dy - O	36337.500	0.1901925
Er - O	35500.000	0.1873276
Gd - O	37562.031	0.1937708
Ho - O	36533.123	0.1886265
La - O	36197.135	0.2069536
Nd - O	37723.987	0.1994694
Sm - O	37224.275	0.1963756
Yb - O	33313.636	0.1854758



Before applying these strains each system's unstrained equilibrium dimensions were determined.

Systems were initially equilibrated in the NVT ensemble for 2.5 ps (using a Berendsen thermostat⁵³ to quickly establish the desired temperature) before Nosé-Hoover NPT dynamics were employed over 100 ps in order that the simulation box could relax to the size appropriate to the applied simulation temperature with no applied strain^{54–56}. This relaxation procedure was performed with no applied pressure (i.e. the barostat pressure was 0 GPa).

The zero strain condition obtained in this manner established the starting point for the strain ramping method, which is now described. Strain was imparted to the system by stretching the simulation box along the [001] direction such that after a 1 ns molecular dynamics simulation, a strain of 0.05 (5%) had been achieved. The length of the simulation box aligned along [001] was updated every 100 fs such that a true strain rate of 0.05 ns⁻¹ was obtained.

Extending the system along the [001] direction results in a decrease in the system dimensions along the [100] and [010] directions (reflecting the system's Poisson's ratio). In order to accurately capture this effect, the simulation barostat was used to hold the [001] axis length at the value determined by the strain ramp whilst still allowing the other box dimensions and angles to vary in order to maintain a system pressure of 0 GPa. In this way the response of the system to the applied strain arising due to its Poisson's ratio was captured, as the x and y simulation box dimensions decreased as a result of the extension in z due to the tensile strain.

At each 0.005 strain increment encountered along the strain-ramp, the state of the system was stored, so that it could be used as the starting point for further simulations. On completion of the ramping method these snapshots were further equilibrated for 1 ns under NPT conditions, (with the [001] aligned cell length still being kept fixed). In this way the relaxed cell dimensions for each combination of dopant, temperature and strain increment were established.

Each data-point in the results given below has been averaged over seven distinct dopant configurations meaning that any bias introduced due to any individual dopant configuration is reduced. As a result, six simulation boxes, in addition to that obtained from the strain-ramp, were produced with different, random, dopant configurations. These were each scaled to give the box dimensions established during the strain-ramp but before performing the NPT equilibration described above. The seven simulation boxes then underwent a final equilibration and data-collection step, which is now described. The equilibration stage consisted of 20 ps of NVT dynamics, which was followed by 1 ns of NVE dynamics during which the system averages used in the results sections were obtained.

Definitions. The activation energies of oxygen migration (or energy barriers) for the thermally activated oxygen diffusion is an important descriptor indicating how low the temperature the electrolyte can effectively function at. In the framework of transition state theory⁵⁷, the oxygen ion exchange rate with vacancies, v , along the migration paths can be described by the Boltzmann relationship as,

$$v = v_0 \exp\left(\frac{-E_a}{k_B T}\right) \quad (3)$$

where E_a denotes the activation energy of migration and v_0 is a constant. The oxygen vacancy diffusivity, D_v , is connected to the mean square displacement $\langle R^2 \rangle$ of the oxygen vacancies via the Einstein relation,

$$\langle R^2 \rangle = 6D_v t \quad (4)$$

D_v exponentially depends on E_a similar to the formalism in eqn (3).

A way to quantify the interaction of point defects within the lattice is by the calculation of their association (or binding energies), E_b , defined by

$$E_b = \sum E_{\text{isolated defects}} - E_{\text{defect cluster}} \quad (5)$$

A positive binding energy implies that the defect cluster is more energetically favourable as compared to the constituent isolated defects.

- Brandon, N. P., Skinner, S. & Steele, B. C. H. Recent advances in materials for fuel cells. *Annu. Rev. Mater. Res.* **33**, 183–213 (2003).
- Fleig, J. Solid oxide fuel cell cathodes: Polarization mechanisms and modelling of the electrochemical performance. *Annu. Rev. Mater. Res.* **33**, 361–382 (2003).
- Solovyov, V. F. *et al.* Highly efficient solid state catalysis by reconstructed (001) ceria surface. *Sci. Rep.* **4**, 4627 (2014).
- Shao, Z. *et al.*, A thermally self-sustained micro solid oxide fuel cell stack with high power density. *Nature* **435**, 795–798 (2005).
- Rupasov, *et al.* Oxygen diffusion in Sr_{0.75}Y_{0.25}CoO_{2.625}: A molecular dynamics study. *Phys. Rev. B* **79**, 172102 (2009).
- Parfitt, D., Chroneos, A., Kilner, J. A. & Grimes, R. W. Molecular dynamics study of oxygen diffusion in Pr₂NiO_{4 + δ}. *Phys. Chem. Chem. Phys.* **12**, 6834–6836 (2010).
- Seymour, I. D. *et al.* Anisotropic oxygen diffusion in PrBaCo₂O_{5.5} double perovskites. *Solid State Ionics* **216**, 41–43 (2012).
- Kushima, A. *et al.* Interstitial diffusion of oxygen in tetragonal La₂CoO_{4 + δ}. *Phys. Chem. Chem. Phys.* **13**, 2242–2249 (2011).
- Steele, B. C. H. & Heinzel, A. Materials for fuel cell technologies. *Nature* **411**, 345–352 (2001).
- Luckyanova, M. L. *et al.* Thermal conductivity control by oxygen defect concentration modification in reducible oxides: The case of Pr_{0.1}Ce_{0.9}O_{2-δ} thin films. *Appl. Phys. Lett.* **104**, 061911 (2014).
- Wang, H., Chroneos, A. & Schwingenschlög, U. Impact of doping on the ionic conductivity of ceria: a comprehensive model. *J. Chem. Phys.* **138**, 224705 (2013).
- Yashima, M. & Takizawa, T. Atomic displacement parameters of ceria doped with rare-earth oxide Ce_{0.8}R_{0.2}O_{1.9} (R = La, Nd, Sm, Gd, Y, and Yb) and correlation with oxide-ion conductivity. *J. Phys. Chem. C* **114**, 2385–2392 (2010).
- Tuller, H. L. Oxygen-ion conduction and structural disorder in conductive oxides. *J. Phys. Chem. Solids* **55**, 1393–1404 (1994).
- Lashtabeg, A. & Skinner, S. J. Solid oxide fuel cells – a challenge for materials chemists. *J. Mater. Chem.* **16**, 3161–3170 (2006).
- Stephens, I. E. L. & Kilner, J. A. Ionic conductivity of Ce_{1-x}Nd_xO_{2-x/2}. *Solid State Ionics* **177**, 669–676 (2006).
- Dholabhai, P. P., Adams, J. B., Crozier, P. & Sharma, R. A density functional study of defect migration in gadolinium doped ceria. *Phys. Chem. Chem. Phys.* **12**, 7904–7910 (2010).
- Sata, N., Eberman, K., Eberl, K. & Maier, J. Mesoscopic fast ion conduction in nanometer-scale planar heterostructures. *Nature* **408**, 946–949 (2000).
- Guo, X. X., Matei, I., Lee, J. S. & Maier, J. Ion conduction across nanosized CaF₂/BaF₂ multilayer heterostructures. *Appl. Phys. Lett.* **91**, 103102 (2007).
- Barriocanal, J. G. *et al.* Colossal ionic conductivity at interfaces of epitaxial ZrO₂:Y₂O₃/SrTiO₃ heterostructures. *Science* **321**, 676–680 (2008).
- Kilner, J. A. Ionic conductors feel the strain. *Nature Mater.* **7**, 838–839 (2008).
- Suzuki, K. *et al.* Molecular dynamics simulation of enhanced oxygen ion diffusion in strained yttria stabilized zirconia. *Appl. Phys. Lett.* **73**, 1502–1504 (1998).
- Dezanneau, G., Hermet, J. & Dupé, B. Effects of biaxial strain on bulk 8% yttria stabilized zirconia ion conduction through molecular dynamics. *Int. J. Hydrogen Energy* **37**, 8081–8086 (2012).
- Kushima, A. & Yildiz, B. Oxygen ion diffusivity in strained yttria stabilized zirconia: Where is the fastest strain. *J. Mater. Chem.* **20**, 4809–4819 (2010).
- De Souza, R. A., Ramadan, A. & Hörner, S. Modifying the barriers for oxygen vacancy migration in fluorite structured CeO₂ electrolytes through strain: A computer simulation study. *Energy Environ. Sci.* **5**, 5445–5453 (2012).
- Rushton, M. J. D., Chroneos, A., Skinner, S. J., Kilner, J. A. & Grimes, R. W. Effect of strain on the oxygen diffusion in yttria and gadolinia co-doped ceria. *Solid State Ionics* **230**, 37–42 (2013).
- Hinterberg, J., Zacherle, T. & De Souza, R. A. Activation volume tensor for oxygen vacancy migration in strained CeO₂ electrolytes. *Phys. Rev. Lett.* **110**, 205901 (2013).
- Marrocchelli, D., Bishop, S. R., Tuller, H. L. & Yildiz, B. Understanding chemical expansion in non-stoichiometric oxides: Ceria and zirconia case studies. *Adv. Funct. Mater.* **22**, 1958–1965 (2012).
- Marrocchelli, D., Bishop, S. R. & Kilner, J. Chemical expansion and its dependence on the host cation radius. *J. Mater. Chem. A* **1**, 7673–7680 (2013).
- Cooper, M. W. D., Rushton, M. J. D. & Grimes, R. W. A many body potential approach to modelling the thermomechanical properties of actinide oxides. *J. Phys. Condens. Matter* **26**, 105401 (2014).
- Xu, H. *et al.* A critical assessment of interatomic potentials for ceria with application to its elastic properties. *Solid State Ionics* **181**, 551–556 (2010).
- Rushton, M. J. D. & Chroneos, A. A critical assessment of interatomic potentials for ceria with application to its elastic properties revisited. *J. Mater. Sci.: Mater. Electron.* **24**, 4590–4592 (2013).
- Finnis, M. W. & Sinclair, J. E. A simple empirical N-body potential for transition metals. *Philos. Mag. A* **50**, 45–55 (1984).
- Daw, M. S. & Baskes, M. I. Semiempirical, quantum mechanical calculation of hydrogen embrittlement in metals. *Phys. Rev. Lett.* **50**, 1285–1288 (1983).
- Daw, M. S. & Baskes, M. I. Embedded-atom method: Derivation and application to impurities, surfaces and other defects in metals. *Phys. Rev. B* **29**, 6443 (1984).
- Born, M. & Huang, K. *Dynamical theory of crystal lattices* (Clarendon Press, Oxford, 1954).
- Pikalova, E. Y. *et al.* CeO₂ based materials doped with lanthanides for applications in intermediate temperature electrochemical devices. *Int. J. Hydrogen Energy* **36**, 6175–6183 (2011).
- Hisashige, T., Yamamura, Y. Y. & Tsuji, T. Thermal expansion and Debye temperature of rare earth doped ceria. *J. Alloys Compd.* **408–412**, 1153–1156 (2006).
- Hong, S. J. & Virkar, A. V. Lattice parameters and densities of rare-earth oxide doped ceria electrolytes. *J. Am. Ceram. Soc.* **78**, 433–439 (1995).
- Omar, S., Wachsmann, E. D., Jones, J. L. & Nino, J. C. Crystal structure ionic conductivity relationships in doped ceria. *J. Am. Ceram. Soc.* **92**, 2674–2681 (2009).
- Zha, S., Xia, C. & Meng, G. Effect of Gd (Sm) doping on properties of ceria electrolyte for solid oxide fuel cells. *J. Power Sources* **115**, 44–48 (2003).
- Kröger, F. A. & Vink, H. J. Relations between the concentrations of imperfections in crystalline solids. *Solid State Phys.* **3**, 307–435 (1956).
- Kilner, J. A. & Waters, C. D. The effects of dopant cation oxygen vacancy complexes on the anion transport properties of non-stoichiometric fluorite oxides. *Solid State Ionics* **6**, 253–259 (1982).
- Steele, B. C. H. Appraisal of Ce_{1-y}Gd_yO_{2-y/2} electrolytes for IT-SOFC operation at 500°C. *Solid State Ionics* **129**, 95–110 (2000).



44. Minervini, L., Zacate, M. O. & Grimes, R. W. Defect cluster formation in M_2O_3 doped CeO_2 . *Solid State Ionics* **116**, 339–349 (1999).
45. Allen, M. P. & Tildesley, D. J. *Computer simulation of liquids* (Oxford University Press, Oxford, 1989).
46. Frenkel, D. & Smit, B. *Understanding molecular simulation: from algorithms to applications* (Elsevier, 2002).
47. Rapaport, D. C. *The art of molecular dynamics simulation* (Cambridge University Press, 2004).
48. Born, M. & Mayer, J. E. Zur gittertheorie der ionenkristalle. *Z. Phys.* **75**, 1–18 (1932).
49. Nelder, J. A. & Mead, R. A Simplex method for function minimization. *Comput. J.* **7**, 308–313 (1965).
50. Hockney, R. W. & Eastwood, J. W. *Computer simulation using particles* (McGraw Hill, New York, 1981).
51. Plimpton, S. Fast parallel algorithms for short-range molecular dynamics. *J. Comput. Phys.* **117**, 1–19 (1995).
52. Plimpton, S. LAMMPS molecular mechanics code. <http://lammps.sandia.gov> (accessed: 16th January 2014).
53. Berendsen, H. J. C., Postma, J. P. M., van Gunsteren, W. F., Di Nola, A. & Haak, J. R. Molecular dynamics with coupling to an external bath. *J. Chem. Phys.* **81**, 3684–3690 (1984).
54. Hoover, W. G. Canonical dynamics: Equilibrium phase-space distributions. *Phys. Rev. B* **31**, 1695 (1985).
55. Nosé, S. A unified formulation of the constant temperature molecular dynamics methods. *J. Chem. Phys.* **81**, 511 (1984).
56. Nosé, S. A molecular dynamics method for simulations in the canonical ensemble. *Mol. Phys.* **52**, 255–268 (1984).
57. Laidler, K. & King, C. Development of transition-state theory. *J. Phys. Chem.* **87**, 2657–2664 (1983).

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M.J.D.R. performed the calculations. M.J.D.R. and A.C. analysed the results and contributed to the discussion.

Additional information

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